

## **isc** Silicon NPN Power Transistor

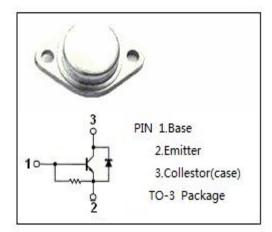
# 2SD951

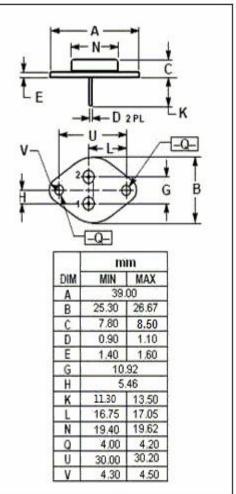
#### DESCRIPTION

- High Breakdown Voltage-
- : V<sub>CBO</sub>= 1500V (Min)
- Low Collector Saturation Voltage-: V<sub>CE(sat)</sub>= 5.0V(Max.)@ I<sub>C</sub>= 2.5A
- Built-in Damper Diode
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### **APPLICATIONS**

• Designed for line-operated horizontal deflection output applications.





### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>сво</sub>	Collector-Base Voltage	1500	V	
V <sub>CES</sub>	Collector-Emitter Voltage	1500	V	
V <sub>EBO</sub>	Emitter-Base Voltage	5	V	
lc	Collector Current- Continuous	3	А	
I <sub>CP</sub>	Collector Current- Peak	5	А	
Pc	Collector Power Dissipation @ T <sub>C</sub> = 25℃	65	W	
TJ	Junction Temperature	130	°C	
T <sub>stg</sub>	Storage Temperature Range	-65~130	°C	



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### ELECTRICAL CHARACTERISTICS

### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 200mA; I <sub>C</sub> = 0	5			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 2.5A; I <sub>B</sub> = 0.8A			5.0	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 2.5A; I <sub>B</sub> = 0.8A			1.5	V
І <sub>сво</sub>	Collector Cutoff Current	V <sub>CB</sub> = 750V; I <sub>E</sub> = 0			50	μA
		V <sub>CB</sub> = 1500V; I <sub>E</sub> = 0			1	mA
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 2.5A; V <sub>CE</sub> = 10V	3		12	
V <sub>ECF</sub>	C-E Diode Forward Voltage	I <sub>F</sub> = 4A			1.7	V
t <sub>stg</sub>	Storage Time			11		μ <b>S</b>
t <sub>f</sub>	Fall Time	I <sub>C</sub> = 2.5A, I <sub>Bend</sub> = 0.8A; L <sub>B</sub> = 5 μ Η			0.9	μ <b>S</b>

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